

Peak Emission Wavelengths: 1460,1720,1900nm
Detector Sensitivity Wavelength Range: 800-2600nm

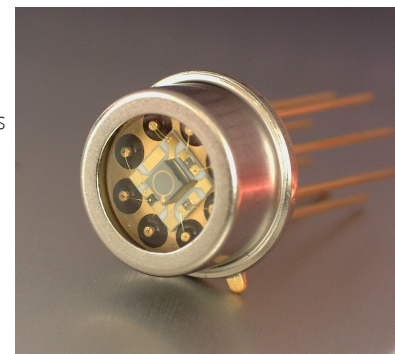
The MTMD1479PD6T38 is a SWIR multi-chip emitter with a InGaAs Photodiode designed for applications requiring various emission sources in a small, densely packaged area. These devices can be custom designed for specific wavelengths and outputs.

FEATURES

- > Hermetically Sealed TO-5 Metal Can Package
- > PIN Photodiode Chip Active Area: 1.0mm
- > High Output Power

APPLICATIONS

- > NDIR / Spectroscopy
- > Medical / Chemical Analysis
- > Biofluorescence Analysis



Emitter Absolute Maximum Ratings (Ta=25°C)



ITEMS	SYMBOL	RATINGS			UNIT
		1460	1720	1900	
Forward Current (DC)	IF	50	50	50	mA
Forward Current (Pulse) *1	IFP	--	--	--	A
Reverse Voltage	VR	5	5	5	V
Power Dissipation	PD	50	50	50	mW
Operating Temperature Range	Topr	-20~+85			°C
Storage Temperature Range	Tstg	-30~+100			°C
Junction Temperature	Tj	100			°C
Lead Soldering Temperature *2	Tls	260			°C

*1: Tw=10µsec, T=10msec. *2: Time 5 Sec max; Position: Up to 3mm from the body.

Emitter Electrical & Optical Characteristics (Ta=25°C)

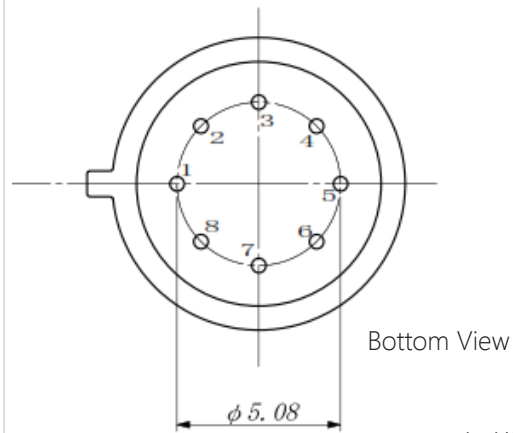
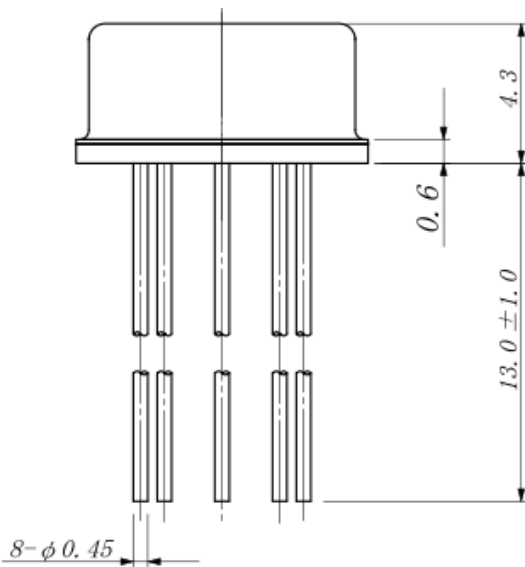
ITEMS	SYMBOL	WAVELENGTH	CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage	VF	1460	IF=50mA	--	1.02	--	V
Forward Voltage	VF	1720	IF=50mA	--	0.96	--	V
Forward Voltage	VF	1900	IF=50mA	--	0.90	--	V
Reverse Current	IR	--	VR=5V	--	--	10	µA
Power Output	PO	1460	IF=50mA	--	2.9	--	mW
Power Output	PO	1720	IF=50mA	--	2.3	--	mW
Power Output	PO	1900	IF=50mA	--	1.9	--	mW

Emitter Electrical & Optical Characteristics (Ta=25°C)

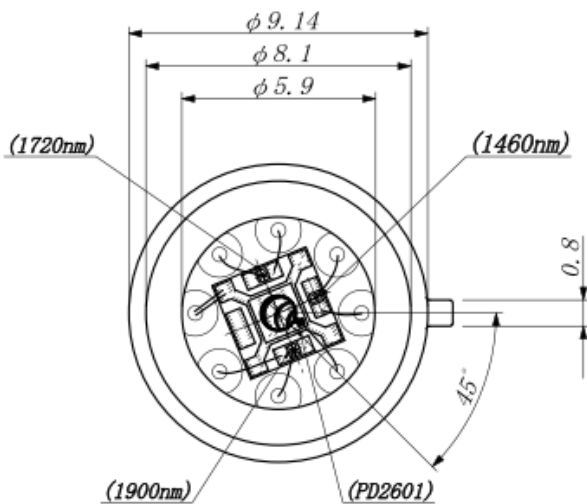
ITEMS	SYMBOL	WAVELENGTH	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Emission Wavelength	λ_p	1460	IF=50mA	--	1460	--	nm
Peak Emission Wavelength	λ_p	1720	IF=50mA	--	1741	--	nm
Peak Emission Wavelength	λ_p	1900	IF=50mA	--	1893	--	nm
Spectral Line Half Width	$\Delta\lambda$	1460	IF=50mA	--	107	--	nm
Spectral Line Half Width	$\Delta\lambda$	1720	IF=50mA	--	141	--	nm
Spectral Line Half Width	$\Delta\lambda$	1900	IF=50mA	--	160	--	nm

Detector Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Breakdown Voltage	VR	IR=100uA	--	--	1	V
Sensitivity Range	λ	VR=0V	600	--	2600	nm
Dark Current	ID	VR=1V	--	--	300	uA
Capacitance	C	VR=0V	--	1000	--	pF
Capacitance	C	VR=1V	--	85	--	pF
Responsivity	R	$\lambda=2400\text{nm}$	--	1.24	--	A/W
Shunt Resistance	RS	VR=10mV	--	3.3	--	MOhm
Quantum Efficiency	QE	$\lambda=1840\text{nm}$	--	72	--	%
Light Current @1300nm	IL	If=10mA	--	30	--	uA
Light Current @1300nm	IL	If=20mA	--	65	--	uA

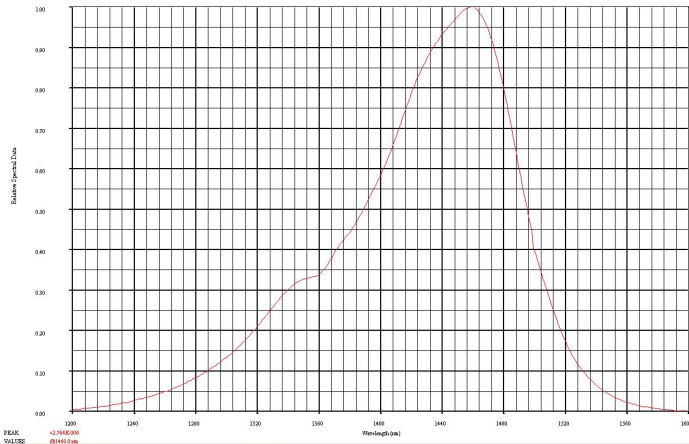


- | | | | | |
|---|---|---|--------------------|--------------------------|
| 1 | → | ↔ | 2 (1460nm) | 3- 1720nm Anode |
| 2 | → | ↔ | 3 (1460nm Cathode) | 4- 1720nm Cathode |
| 3 | → | ↔ | 4 (1720nm) | 5- PD2601 Cathode (Case) |
| 6 | → | ↔ | 7 (1900nm) | 6- 1900nm Anode |
| 5 | → | ↔ | 8 (PD2601) | 7- 1900nm Cathode |
| | | | | 8- PD2601 Anode |

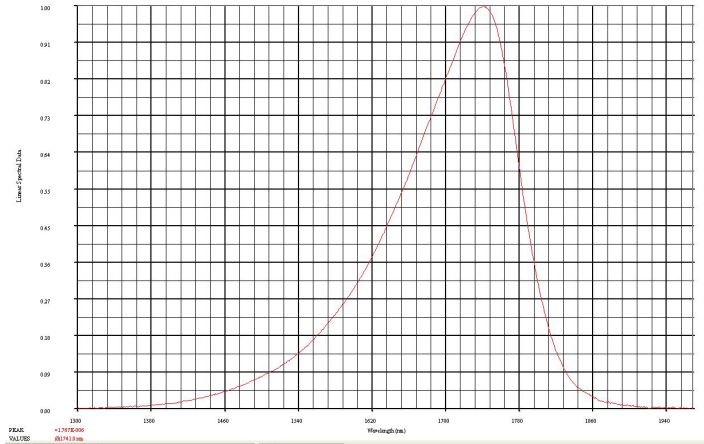


Unit: mm, Tolerance: ± 0.2

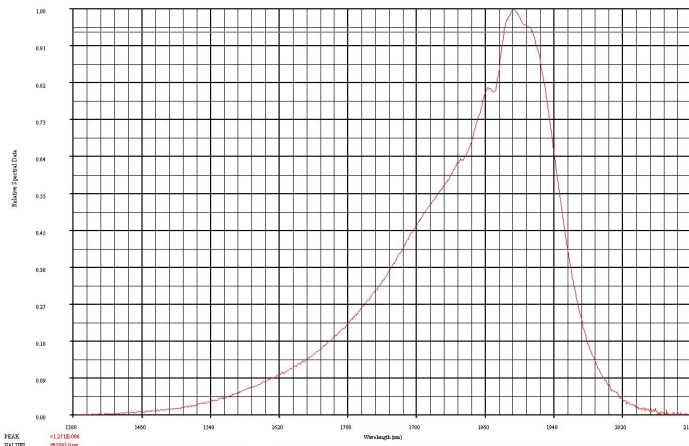
1460nm Spectral Response



1720nm Spectral Response



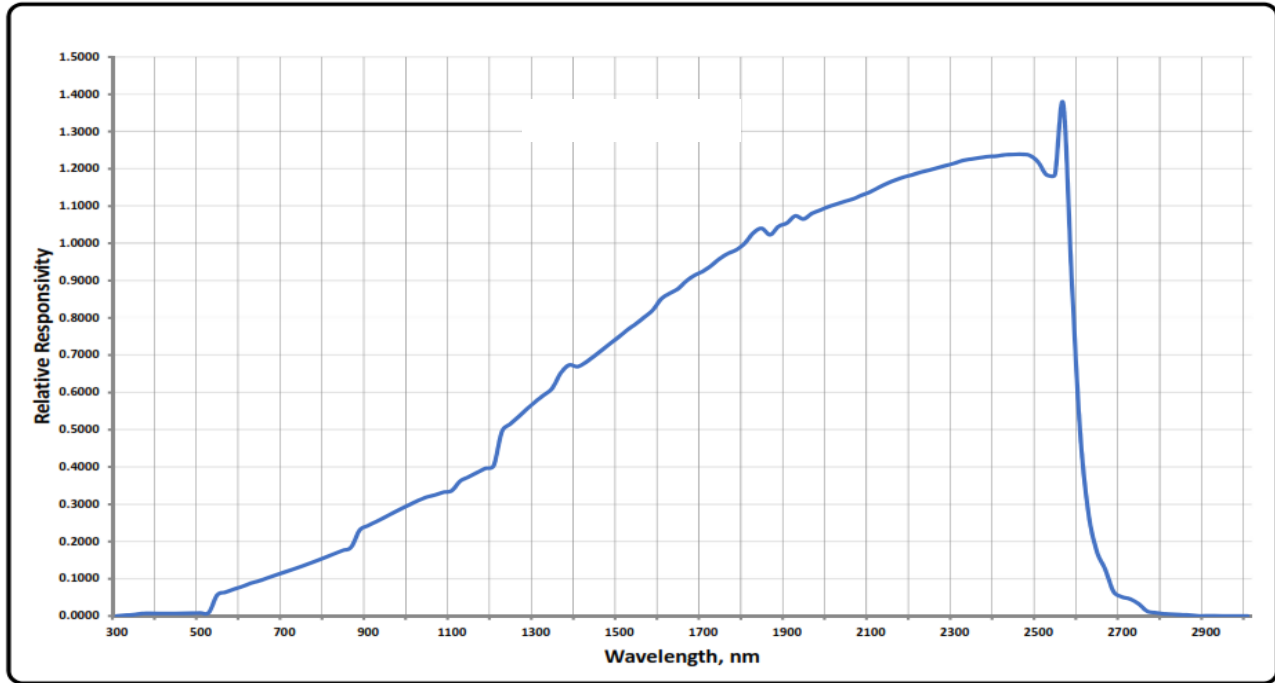
1900nm Spectral Response



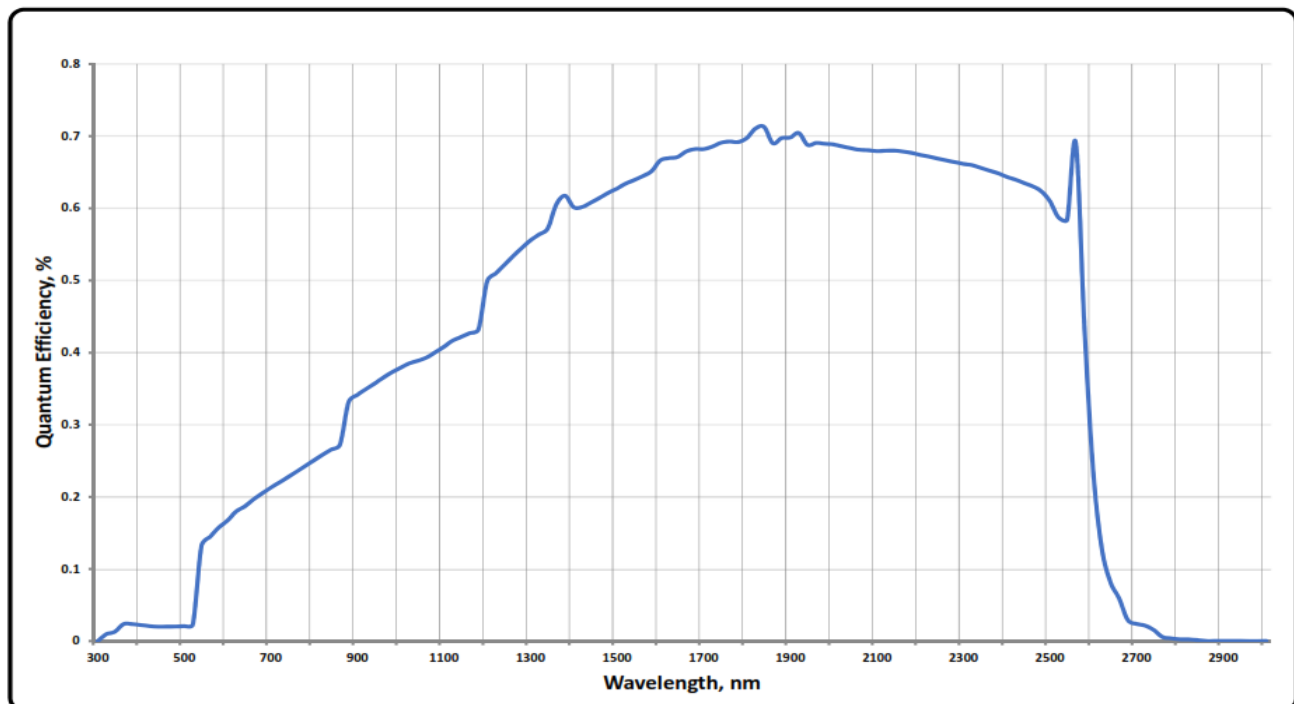
The information contained herein is subject to change without notice.

2023-10-30

Spectral Responsivity



Quantum Efficiency



The information contained herein is subject to change without notice.

2023-10-30